

DESCRIPTION

The A6500B is designed for portable applications with demanding performance and space requirements. The A6500B performance optimized for battery-powered systems to deliver ultra-low noise and low quiescent current. Regulator ground current increases only slightly in dropout, further prolonging the battery life. The A6500B also works with low-ESR ceramic capacitors, reducing the amount of board space necessary for power applications, critical in hand-held wireless devices. The A6500B consumes only 0.1µA current in shutdown mode and has fast turn-on time (Typical 100µs). The other features include ultra- low dropout voltage, high output accuracy, current limiting protection, and high ripple rejection ratio.

A6500B is available in SOT-25 and DFN4 (1x1) packages.

ORDERING INFORMATION

Package Type	Part Number		
SOT-25	E5	A6500BE5R-XX	
SPQ: 3,000pcs/Reel	EO	A6500BE5VR-XX	
DFN4(1x1)	J4	A6500BJ4R-XX	
SPQ: 5,000pcs/Reel	J4	A6500BJ4VR-XX	
	XX: Output Voltage		
Note	10=1.0V, 33=3.3V		
Note	V: Halogen free Package		
	R: Tape & Reel		
AiT provides all RoHS products			

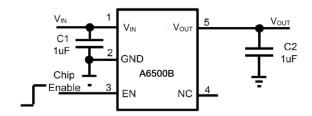
FEATURES

- Ultra-low Noise
- Ultra-Fast Transient Response
- High PSRR: -87dB @ 217Hz
 - -83dB @ 1kHz
 - -54dB @ 1MHz
- 0.1µA Standby Current When Shutdown
- Low Dropout: 240mV@500mA (V_{OUT}=2.8V)
- Wide Operating Voltage Ranges: 1.8V to 5.5V
- Current Limiting and Short Circuit
 Current Protection
- Thermal Shutdown Protection
- Only 1µF Output Capacitor Required for Stability
- Fast output discharge
- Available in SOT-25 and DFN4 (1x1) packages

APPLICATION

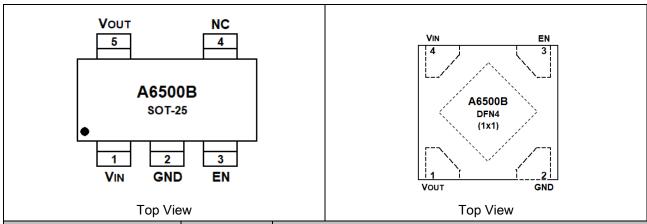
- Cellular and Smart Phones
- Cordless Telephones
- Camera and Machine Vision Modules
- Battery-Powered Equipment
- Laptop, Palmtops, Notebook Computers
- Hand-Held Instruments

TYPICAL APPLICATION CIRCUIT





PIN DESCRIPTION



F	Pin#	Cumbal	Eunstion		
SOT-25	DFN4(1x1)	Symbol	Function		
1	4	V _{IN}	Power Input Voltage		
2	2	GND	Ground		
3	3	EN	Chip Enable Pin. This pin has an internal pull-down resistor		
4	-	NC	No Connection		
5	1	V _{OUT}	Output Voltage		
	Exposed		The exposed pad should be connected to a large ground		
-	Pad	-	plane to maximize thermal performance		

ABSOLUTE MAXIMUM RATINGS

V _{IN} , Input Supply Voltage	-0.3V~+6V
EN Pin Input Voltage	-0.3V ~ VIN
Output Voltages	$-0.3V \sim V_{IN} + 0.3V$
Output Current	500mA
Maximum Junction Temperature	150°C
Operating Temperature RangeNOTE1	-40°C ~ 85°C
Storage Temperature Range	-65°C ~ 125°C
Lead Temperature (Soldering, 10s)	300°C

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

NOTE1: The A6500B is guaranteed to meet performance specifications from 0°C to 70°C. Specifications over the -40°C to 85°C operating temperature range are assured by design, characterization and correlation with statistical process controls.

THERMAL RESISTANCENOTE2

Package	θја	θις
SOT-25	250°C/W	130°C/W

NOTE2: Thermal Resistance is specified with approximately 1 square of 1 oz copper.



ELECTRICAL CHARACTERISTICSNOTE3

VIN=VOUT +1V, EN=VIN, CIN=COUT=1µF, TA=25°C, unless otherwise noted.

Param	eter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Input Voltage		V _{IN}		1.8	-	5.5	V	
Output Voltage Ad	ccuracy	ΔVουτ	V _{IN} =V _{OUT} +1V, I _{OUT} =1mA	-2	-	+2	%	
Current Limit		I _{LIM}	R _{LOAD} =1Ω	550	-	-	mA	
Short Circuit Curre	ent	Ishort	V _{OUT} =0V	-	200	-	mA	
Quiescent Curren	t	ΙQ	V _{EN} >1.2V, I _{OUT} =0mA	-	45	70	μΑ	
			І _{ОUТ} =500mA, V _{ОUТ} =3.3V	-	220	320		
Drama, it Valtage		M	I _{ОUТ} =500mA, V _{ОUТ} =2.8V	-	240	360	mV	
Dropout Voltage		V_{DROP}	I _{ОUТ} =500mA, V _{ОUТ} =1.8V	-	360	520		
			I _{ОUТ} =500mA, V _{ОUТ} =1.0V	-	700	1000]	
Line DescriptionNC	TE4	A)/	V _{IN} =V _{OUT} +1V to 5.5V		0.00	0.17	%/V	
Line Regulation ^{NO}	71L4	ΔV_{LINE}	I _{OUT} =1mA	-	0.03			
Load DegulationN	OTE5	۸۱/، - ، -	1mA <i<sub>OUT<300mA</i<sub>		0.000	-	%mA	
Load Regulation ^N	O1E3	ΔV_{LOAD}	V _{IN} =V _{OUT} +1V	-	0.002			
Output Voltage		ТСуоит	= 1m Λ	-	±60	-	ppm/°C	
Temperature Coe	fficient ^{NOTE6}		I _{OUT} =1mA					
Standby Current		Istby	V _{EN} =GND, Shutdown	-	0.1	1	μA	
EN Input Bias Cur	rent	I _{IBSD}	V _{EN} =GND or V _{IN}	-	0.1	1	μA	
EN Input	Logic Low	V _{IL}	V _{IN} =3V to 5.5V, Shutdown	-	-	0.4	V	
Threshold	Logic High	ViH	V _{IN} =3V to 5.5V, Start up	1.2	-	-	V	
			10 to100kHz; C _{OUT} =1uF		50			
Output Noise	Output Noise		I _{ОUТ} =100mA;V _{ОUТ} =2.8V	-	50	-	μV _{RMS}	
Voltage		e no	10 to100kHz; Соит=1uF		38	-		
			I _{ОUT} =100mA; V _{ОUT} =1.8V	-				
	f=217Hz			-	-87	-		
Power Supply	f=1kHz	DCDD	I _{OUT} =10mA, V _{OUT} =1.8V,	-	-83	-	4D	
Rejection Ratio	f=10kHz	PSRR	V _{IN} =2.8V	-	-72	-	dB	
	f=1MHz			-	-54	1		
Thermal Shutdow	Thermal Shutdown Temperature		Shutdown, Temp increasing	-	170	-	°C	
Thermal Shutdown Hysteresis		T _{SDHY}		-	25	-	°C	

NOTE4: Production test at +25°C. Specifications over the temperature range are guaranteed by design and characterization.

NOTE7: The temperature coefficient is calculated by TC $_{VOUT}$ = ΔV_{OUT} /(ΔTxV_{OUT})

NOTE5: Line regulation is calculated by y $\Delta V_{\text{LINE}} = [(V_{\text{OUT1}} - V_{\text{OUT2}})/(\Delta V_{\text{IN}} x V_{\text{OUT(normal)}})]x100$

Where V_{OUT1} is the output voltage when V_{IN}=5.5V, and V_{OUT2} is the output voltage when V_{IN}=4.3V, ∆V_{IN}=1.2V. V_{OUT (normal)} =3.3V.

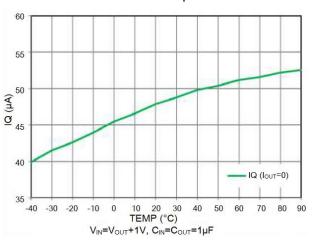
NOTE6: Load regulation is calculated by ΔV_{LOAD} = [(V_{OUT1} - V_{OUT2})/($\Delta I_{OUT}xV_{OUT(normal)}$)]x100

Where V_{OUT1} is the output voltage when I_{OUT} =1mA, and V_{OUT2} is the output voltage when I_{OUT} =300mA. ΔI_{OUT} =299mA, $V_{OUT(normal)}$ =2.8V.

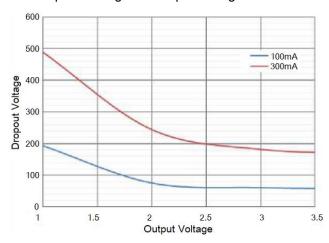


TYPICAL PERFORMANCE CHARACTERISTICS

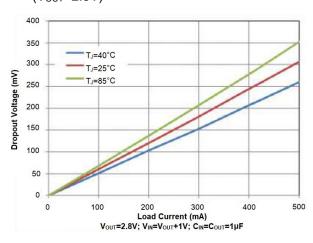
1. Quiescent Current vs Temperature



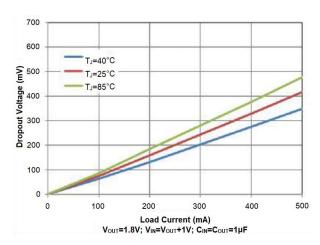
2. Dropout Voltage vs. Output Voltage



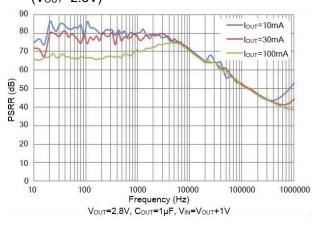
Output Dropout Voltage vs Load Current (V_{OUT}=2.8V)



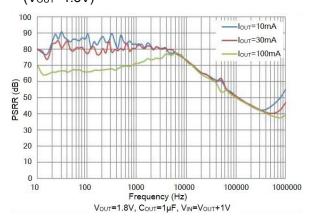
4. Dropout Voltage vs Load Current (V_{OUT}=1.8V)



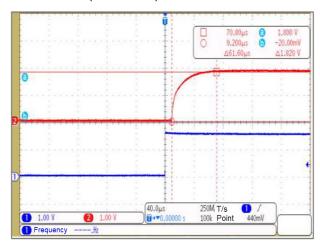
Power-Supply Ripple Rejection vs Frequency (V_{OUT}=2.8V)



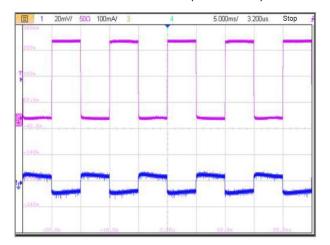
6. Power-Supply Ripple Rejection vs. Frequency (Vout=1.8V)



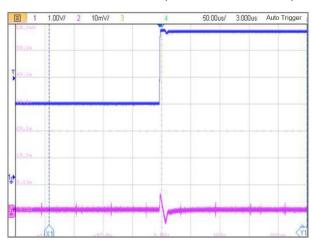
7. EN Start (Vout=1.8V)



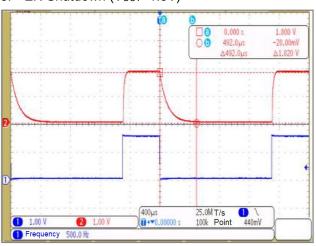
9. Load Trans 1mA \sim 300mA (V_{OUT}= 1.8V)



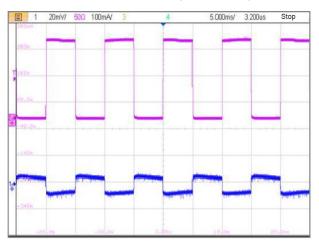
11. Line Trans 2.8V~5.5V (Vout=1.8V,Iout=1mA)



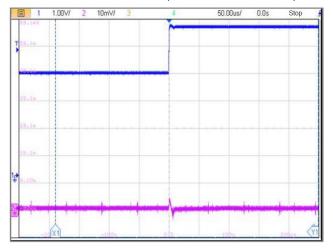
8. EN Shutdown (Vout=1.8V)



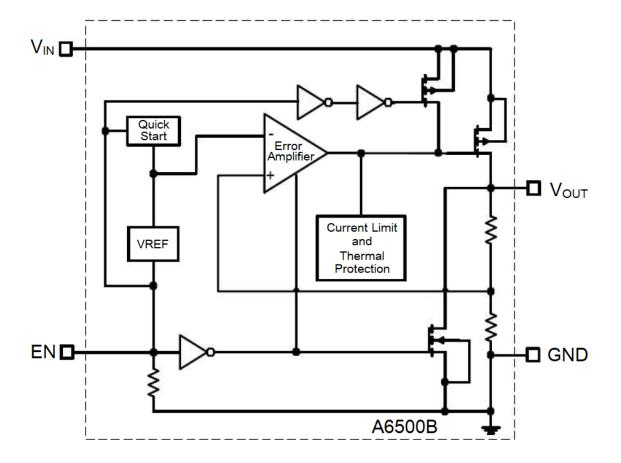
10. Load Trans 1mA \sim 300mA (V_{OUT}= 2.8V)



12. Line Trans 3.8V~5.5V (Vout=2.8V,Iout=1mA)



BLOCK DIAGRAM





DETAILED INFORMATION

Applications Information

Like any low-dropout regulator, the external capacitors used with the A6500B must be carefully selected for regulator stability and performance. Using a capacitor whose value is > 1μF on the A6500B input and the amount of capacitance can be increased without limit. The input capacitor must be located a distance of not more than 0.5 inch from the input pin of the IC and returned to a clean analog ground. Any good quality ceramic or tantalum can be used for this capacitor. The capacitor with larger value and lower ESR (equivalent series resistance) provides better PSRR and line-transient response. The output capacitor must meet both requirements for minimum amount of capacitance and ESR in all LDOs application. Generally, 1.0-μF X7R-type ceramic capacitors are recommended because these capacitors have minimal variation in value and equivalent series resistance (ESR) over temperature. Output capacitor of larger capacitance can reduce noise and improve load transient response, stability and PSRR. The output capacitor should be located not more than 0.5 inch from the V_{OUT} pin of the A6500B and returned to a clean analog ground.

Enable Function

The A6500B features an LDO regulator enable/disable function. To assure the LDO regulator will switch on; the EN turn on control level must be greater than 1.2 volts. The LDO regulator will go into the shutdown mode when the voltage on the EN pin falls below 0.4 volts. For to protect the system, the A6500B have a quick discharge function. If the enable function is not needed in a specific application, it may be tied to V_{IN} to keep the LDO regulator in a continuously on state.

Thermal Considerations

Thermal protection limits power dissipation in A6500B. When the operation junction temperature exceeds 170°C, the OTP circuit starts the thermal shutdown function turn the pass element off. The pass element turns on again after the junction temperature cools by 25°C.

For continue operation, do not exceed absolute maximum operation junction temperature 125°C. The power dissipation definition in device is:

$$P_{D(MAX)} = (T_{J(MAX)} - T_A)/\theta_{JA}$$

Where $T_{J(MAX)}$ is the maximum operation junction temperature 125°C, T_A is the ambient temperature and the θ_{JA} is the junction to ambient thermal resistance. For recommended operating conditions specification of A6500B, where $T_{J(MAX)}$ is the maximum junction temperature of the die (125°C) and T_A is the maximum ambient temperature. The junction to ambient thermal resistance (θ_{JA} is layout dependent) for SOT-25



package is 250° C/W, on standard JEDEC 51-3 thermal test board. The maximum power dissipation at T_A= 25° C can be calculated by following formula:

$$P_{D(MAX)} = (125^{\circ}C - 25^{\circ}C)/250 = 400 \text{mW (SOT-25)}$$

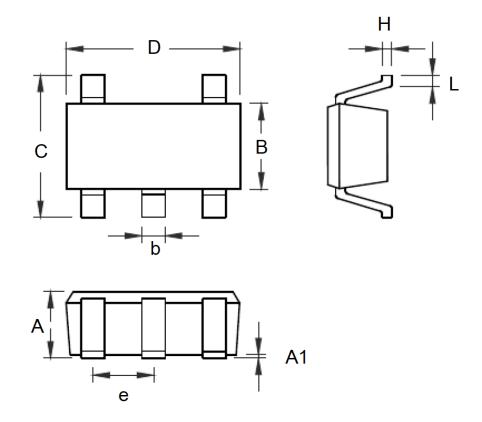
Layout considerations

To improve ac performance such as PSRR, output noise, and transient response, it is recommended that the PCB be designed with separate ground planes for V_{IN} and V_{OUT} , with each ground plane connected only at the GND pin of the device.



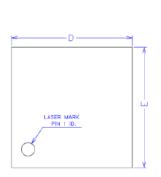
PACKAGE INFORMATION

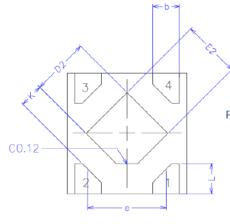
Dimension in SOT-25 (Unit: mm)



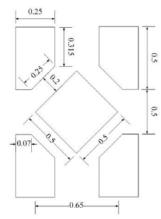
Symbol	Millim	neters	Inches		
	Min	Max	Min	Max	
Α	0.889	1.295	0.035	0.051	
A1	0.000	0.152	0.000	0.006	
В	1.397	1.803	0.055	0.071	
b	0.356	0.559	0.014	0.022	
С	2.591	2.997	0.102	0.118	
D	2.692	3.099	0.106	0.122	
е	0.838	1.041	0.033	0.041	
Н	0.080	0.254	0.003	0.010	
L	0.300	0.610	0.012	0.024	

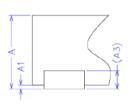
Dimension in DFN4(1x1) (Unit: mm)

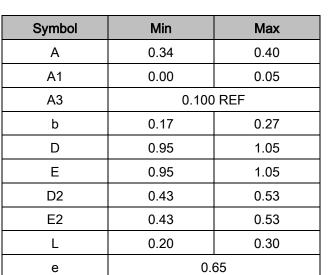












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